SC82 120mA LDO REGULATOR
R1141Q SERIES

■ OUTLINE

The R1141Q Series are voltage regulator ICs with high output voltage accuracy, low supply current, low ON-resistance, and high ripple rejection by CMOS process. Each of these voltage regulator ICs consists of a voltage reference unit, an error amplifier, resistors for setting Output Voltage, a current limit circuit, and a chip enable circuit.
Output Current Limit circuit is embedded in the R1141Q Series to prevent the break down of the IC caused by excess current. Chip enable circuit realizes standby mode and makes consumption current extremely small.
These ICs perform with low dropout voltage and a chip enable function. The line transient response and load transient response of the R1141Q Series are excellent, thus these ICs are very suitable for the power supply for hand-held communication equipment.
The output voltage of these ICs is internally fixed with high accuracy. Since the package for these ICs is SC-82AB (Super Mini-mold) package, high density mounting of the ICs on boards is possible.

■ FEATURES

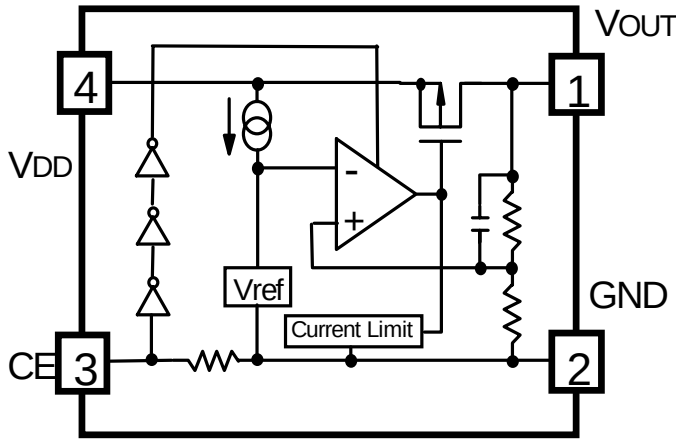
- Ultra-Low Supply Current..... TYP. 90µA
- Standby Mode ..... TYP. 0.1µA
- Low Dropout Voltage ..... TYP. 0.15V(I_{OUT}=100mA Output Voltage=3.0V Type)
- High Ripple Rejection ..... TYP. 75dB(V_{OUT}≤2.4V),70dB(V_{OUT}≥2.5V) (f=1kHz)
- Low Temperature-Drift Coefficient of Output Voltage TYP. ±100ppm/°C
- Excellent Line Regulation ..... TYP. 0.05%/V
- High Output Voltage Accuracy..... ±1.5% or ±30mV(V_{OUT}≤2.0V)
- Excellent Dynamic Response
- Small Package .....SC-82AB(Super Mini-mold)
- Output Voltage.....Stepwise setting with a step of 0.1V in the range of 1.5V to 4.0V is possible
- Built-in chip enable circuit (B/D: active high)
- Built-in fold-back protection circuit.....TYP. 40mA (Current at short mode)
- Ceramic capacitor can be used for Output pin.....Recommended value is 2.2µF or more.

■ APPLICATIONS

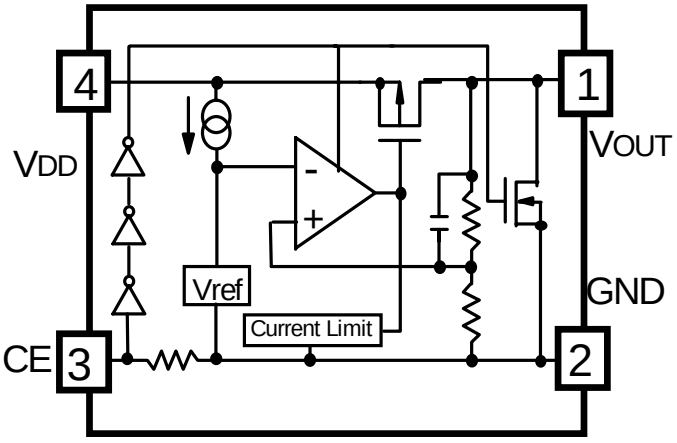
- Power source for cellular phones such as GSM, CDMA and various kinds of PCS.
- Power source for electrical appliances such as cameras, VCRs, camcorders, and hand-held communication equipment.
- Power source for battery-powered equipment.
- Very stable Voltage Reference

■ BLOCK DIAGRAM

R1141QXX1B



R1141QXX1D



■ SELECTION GUIDE

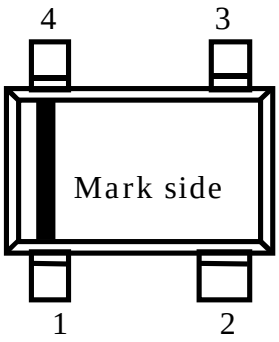
The output voltage, mask option, and the taping type for the ICs can be selected at the user's request. The selection can be made with designating the part number as shown below;

R1141QXX1X-XX ←Part Number
↑ ↑ ↑ ↑
a b c d

Code	Contents
a	Designation of Package Type : Q:SC82-AB (Super Mini-mold)
b	Setting Output Voltage (V_{OUT}) : Stepwise setting with a step of 0.1V in the range of 1.5V to 4.0V is possible.
c	Designation of Mask Option : B: Without auto discharge function at OFF state. D: With auto discharge function at OFF state.
d	Designation of Taping Type : Ex. TR, TL (refer to Taping Specifications; TR type is the standard direction.)

■ PIN CONFIGURATION

SC-82AB



■ PIN DESCRIPTION

Pin No.	Symbol	Description
1	V_{OUT}	Output pin
2	GND	Ground Pin
3	CE	Chip Enable Pin
4	V_{DD}	Input Pin

■ ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Rating	Unit
Input Voltage	V_{IN}	6.5	V
Input Voltage(CE Pin)	V_{CE}	-0.3 ~ V_{IN}+0.3	V
Output Voltage	V_{OUT}	-0.3 ~ V_{IN}+0.3	V
Output Current	I_{OUT}	140	mA
Power Dissipation	P_D	150	mW
Operating Temperature Range	Topt	-40 ~ 85	°C
Storage Temperature Range	Tstg	-55 ~ 125	°C

■ ELECTRICAL CHARACTERISTICS

● R1141QXX1B/R1141QXX1D

Topt=25°C

Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
V_{OUT}	Output Voltage	V_{IN} = Set V_{OUT}+1V 1mA ≤ I_{OUT} ≤ 30mA(Note 1)	V_{OUT} ×0.985 (-30mV)		V_{OUT} ×1.015 (+30mV)	V
I_{OUT}	Output Current	V_{IN} - V_{OUT} = 1.0V	120			mA
$\Delta V_{OUT}/\Delta I_{OUT}$	Load Regulation	V_{IN} = Set V_{OUT}+1V 1mA ≤ I_{OUT} ≤ 120mA		12	40	mV
V_{DIF}	Dropout Voltage	Refer to the ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE				
I_{SS}	Supply Current	V_{IN} = Set V_{OUT}+1V		90	160	µA
Istandby	Supply Current (Standby)	V_{IN} = V_{CE} = Set V_{OUT}+1V		0.1	1.0	µA
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	Set V_{OUT}+0.5V ≤ V_{IN} ≤ 6V I_{OUT} = 30mA (In case that V_{OUT}≤1.6V, 2.2V≤ V_{IN} ≤ 6V)		0.05	0.10	%/V
RR	Ripple Rejection	f = 1kHz, Ripple 0.5Vp-p V_{IN} = Set V_{OUT}+1V, I_{OUT} = 30mA (In case that V_{OUT}≤1.7V, V_{IN} -V_{OUT} =1.2V)		75 (70) (Note 2)		dB
V_{IN}	Input Voltage		2.2		6.0	V
$\Delta V_{OUT}/\Delta T$	Output Voltage Temperature Coefficient	I_{OUT} = 30mA -40°C ≤ Topt ≤ 85°C		±100		ppm /°C
Ilim	Short Current Limit	V_{OUT} = 0V		40		mA
R_{PU}	$\overline{CE}$ Pull-up Resistance		0.7	2.0	8.0	MΩ
V_{CEH}	$\overline{CE}$ Input Voltage "H"		1.5		V_{IN}	V
V_{CEL}	$\overline{CE}$ Input Voltage "L"		0.0		0.3	V
en	Output Noise	BW=10Hz to 100kHz		30		µVrms
RLOW	Low Output Nch Tr. ON Resistance (of D version)	V_{CE}=0V		60		Ω

Note 1: ±30mV Tolerance at V_{OUT}≤2.0V

Note 2:70dB at V_{OUT}≥2.5V

● ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE

Topt = 25°C

Output Voltage V_{OUT} (V)	Dropout Voltage V_{DIF} (V)		
	Condition	TYP.	MAX.
V_{OUT} = 1.5	I_{OUT} = 120mA	0.36	0.70
V_{OUT} = 1.6		0.32	0.60
V_{OUT} = 1.7		0.30	0.50
1.8 ≤ V_{OUT} ≤ 2.0		0.28	0.40
2.1 ≤ V_{OUT} ≤ 2.7		0.24	0.35
2.8 ≤ V_{OUT} ≤ 4.0		0.18	0.28

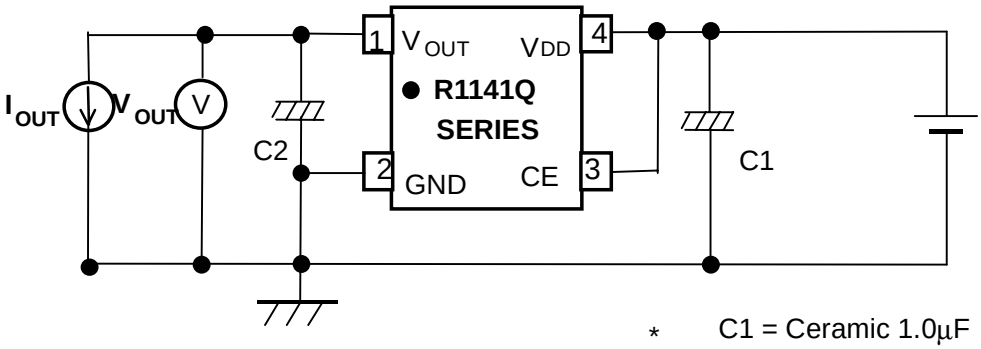
■ TECHNICAL NOTES

When using these ICs, consider the following points:

Phase Compensation
In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, be sure to use a 2.2µF or more capacitor COUT with good frequency characteristics and ESR (Equivalent Series Resistance). (Note: When the additional ceramic capacitors are connected to the Output Pin with Output capacitor for phase compensation, the operation might be unstable. Because of this, test these ICs with as same external components as ones to be used on the PCB.)

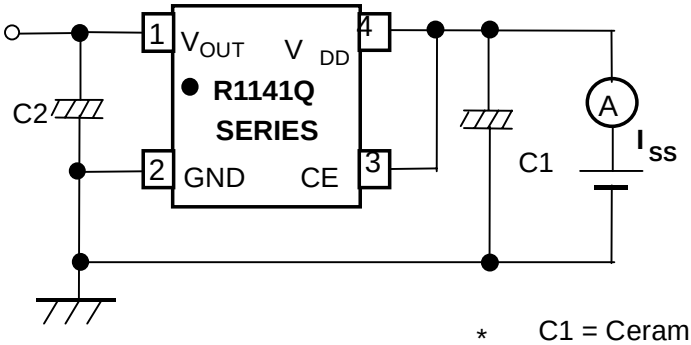
PCB Layout
Make VDD and GND line sufficient. When the impedance of these is high, it would be a cause of picking up the noise or unstable operation. Connect a capacitor with as much as 1.0µF capacitor between VDD and GND pin as close as possible. Set external components, especially output capacitor as close as possible to the ICs and make wiring shortest.

■ TEST CIRCUITS



* C1 = Ceramic 1.0µF
C2 = Ceramic 2.2µF

Fig.1 Standard test Circuit



* C1 = Ceramic1.0µF
C2 = Ceramic 2.2µF

Fig.2 Supply Current Test Circuit

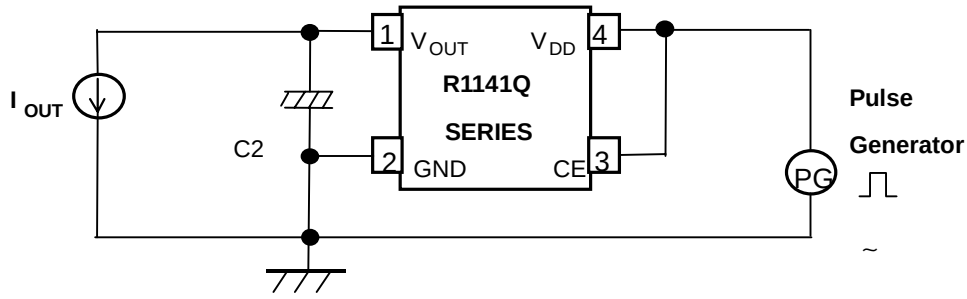
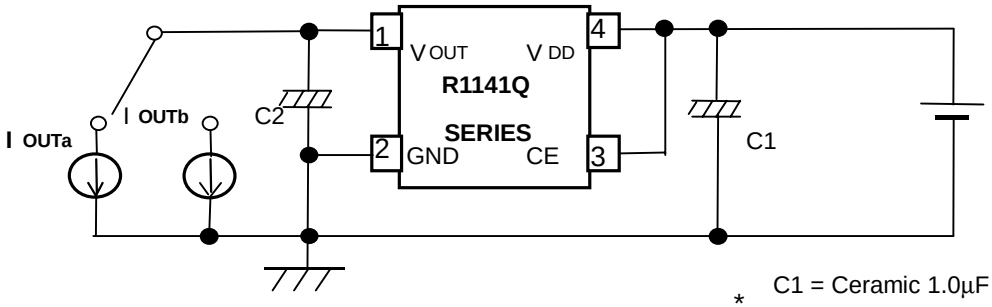


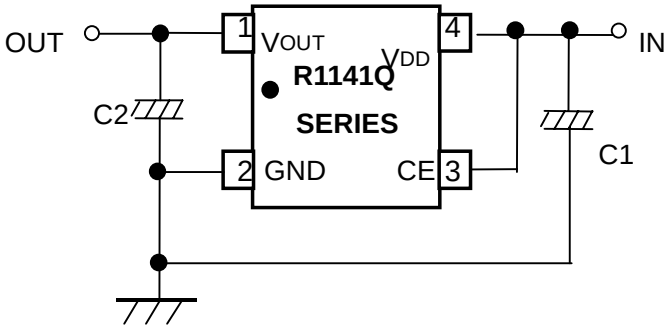
Fig.3 Ripple Rejection, Line Transient Response Test Circuit



* C1 = Ceramic 1.0µF
C2 = Ceramic 2.2µF

Fig.4 Load Transient Response Test Circuit

■ TYPICAL APPLICATION



(External Components)
Output Capacitor; Ceramic Type C1=1µF C2=2.2µF

■ TYPICAL CHARACTERISTICS

1) Output Voltage vs. Output Current

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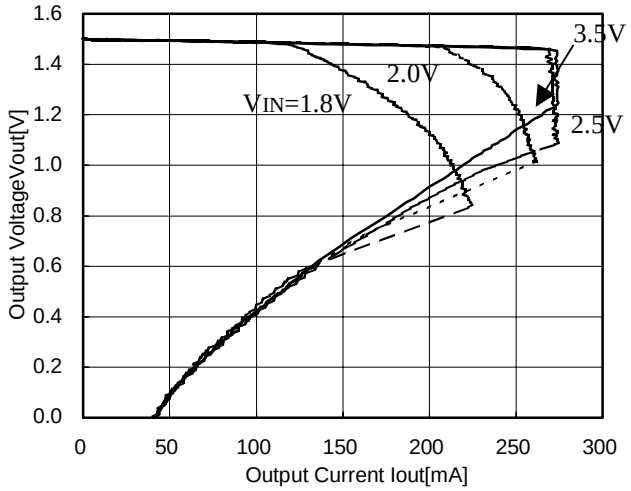

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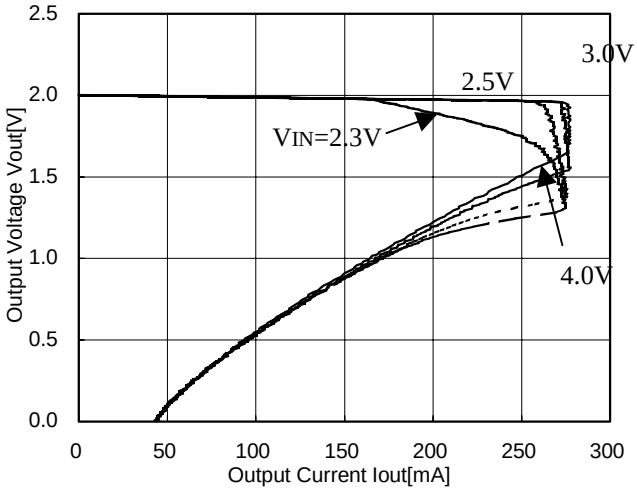

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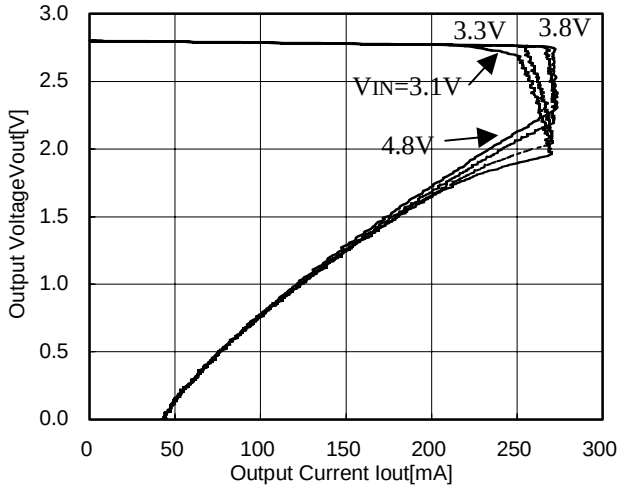

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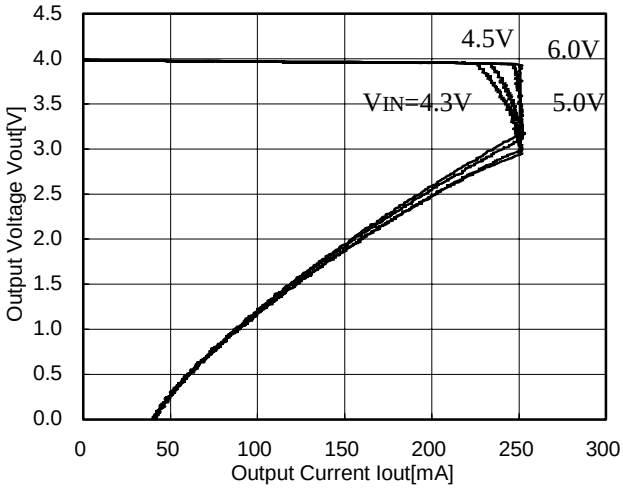

2) Output Voltage vs. Input Voltage

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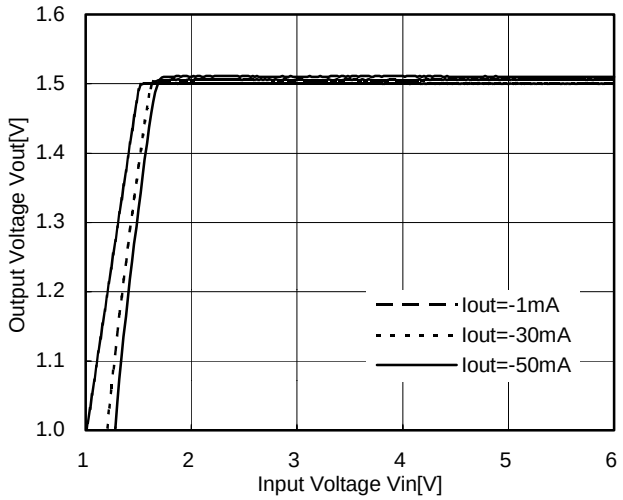

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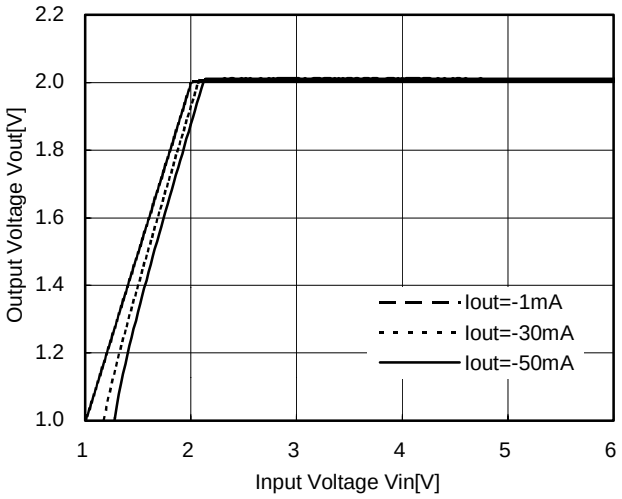

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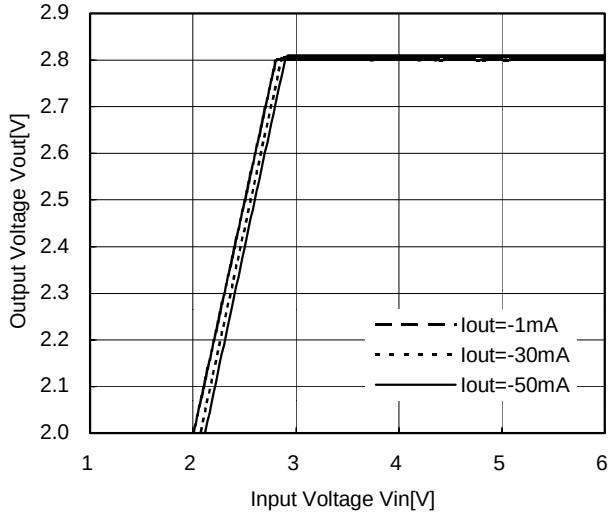

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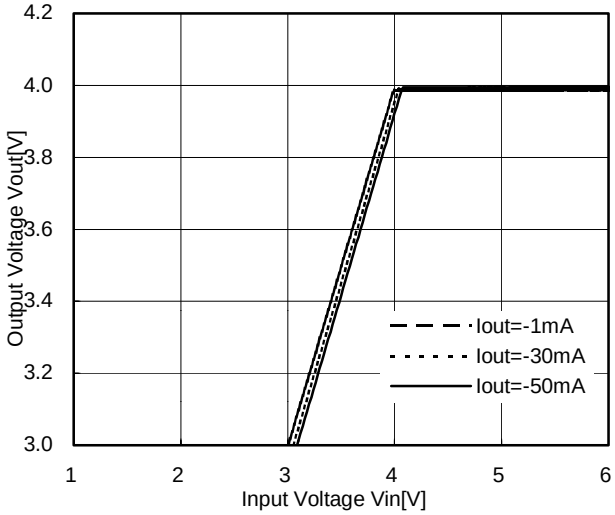

3) Dropout Voltage vs. Output Current

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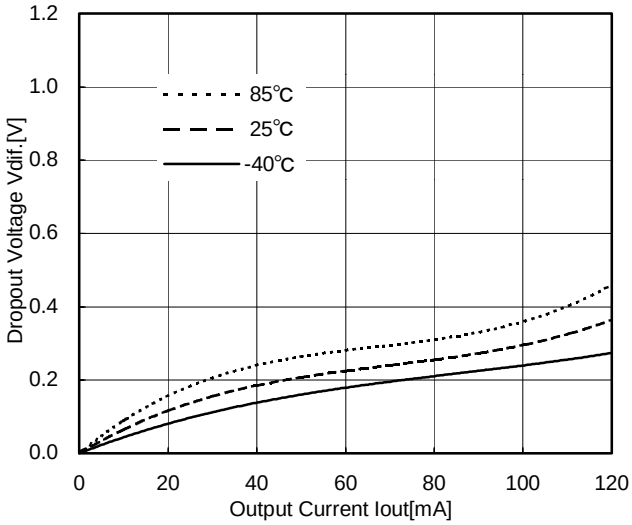

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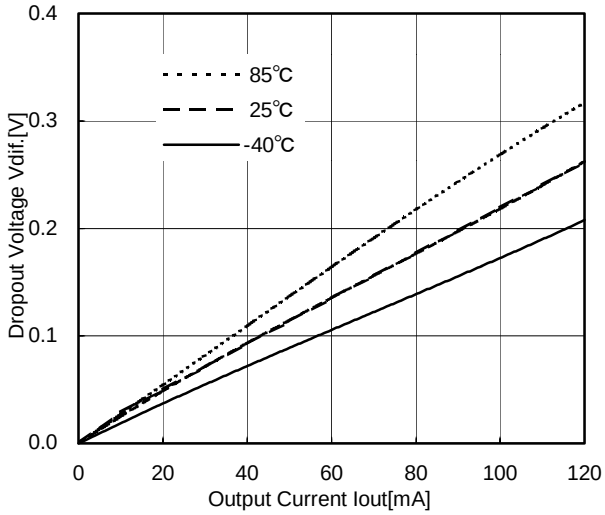

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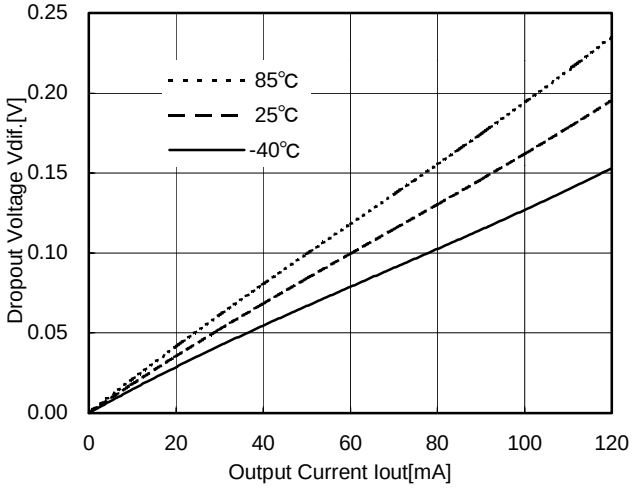

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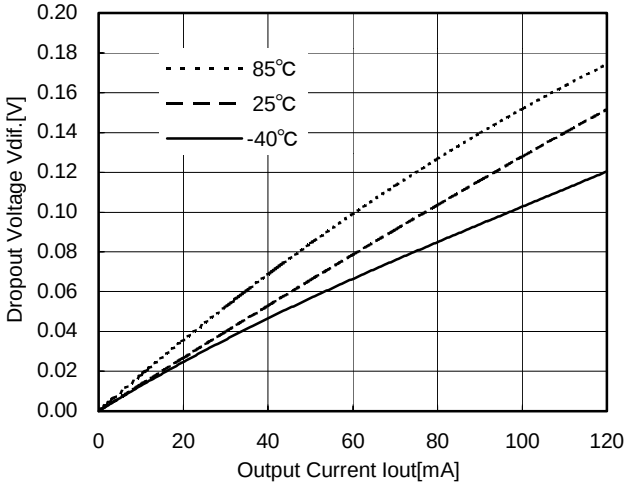

4) Output Voltage vs. Temperature

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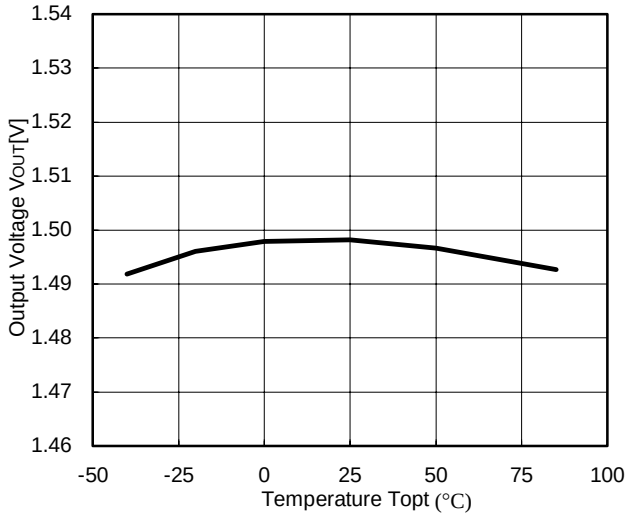
V_{IN}=2.5V, I_{OUT}=30mA



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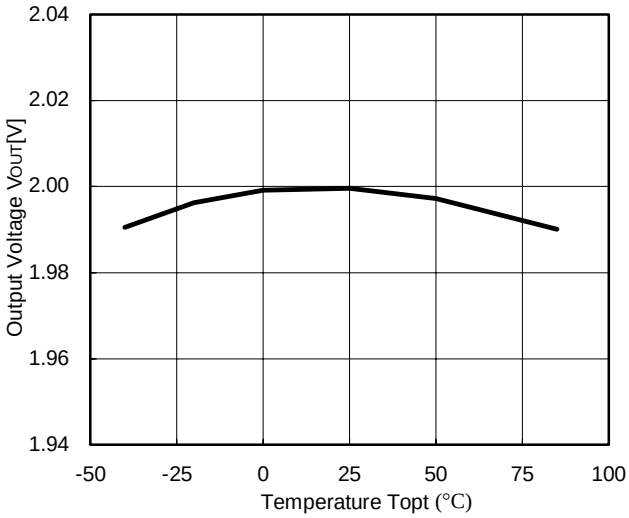
V_{IN}=3.0V, I_{OUT}=30mA



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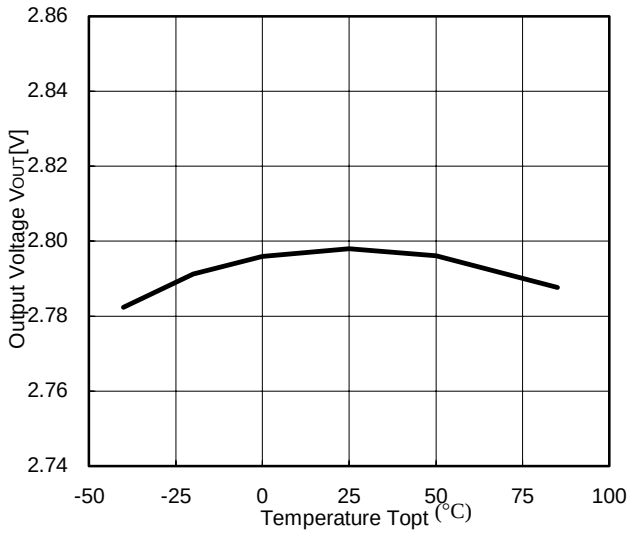
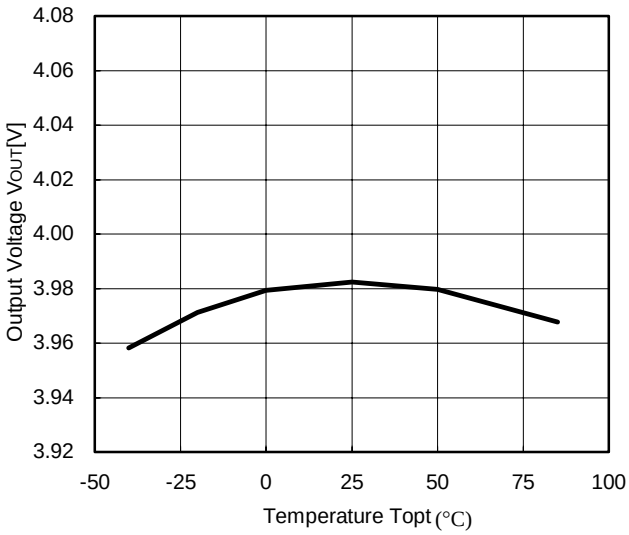
V_{IN}=3.8V, I_{OUT}=30mA

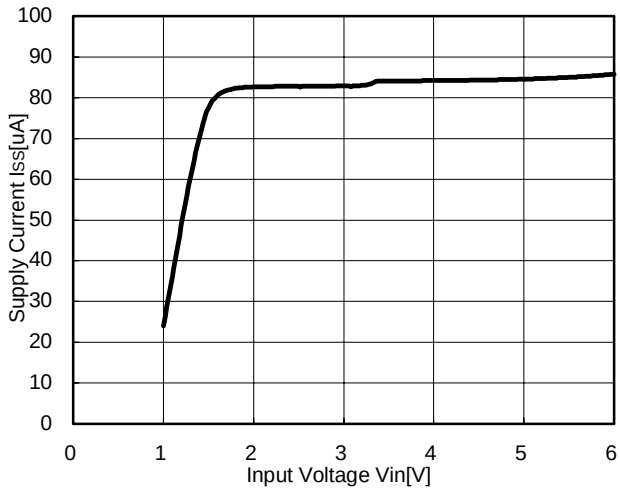


R1141Q401X
V_{IN}=5.0V, I_{OUT}=30mA



5) Supply Current vs. Input Voltage (Topt=25°C)

R1141Q151X



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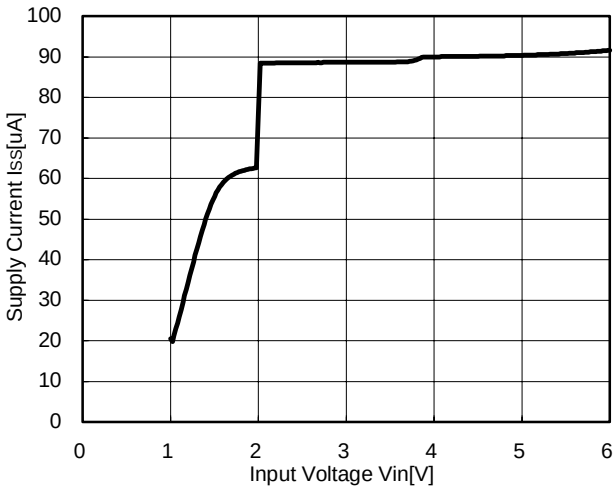

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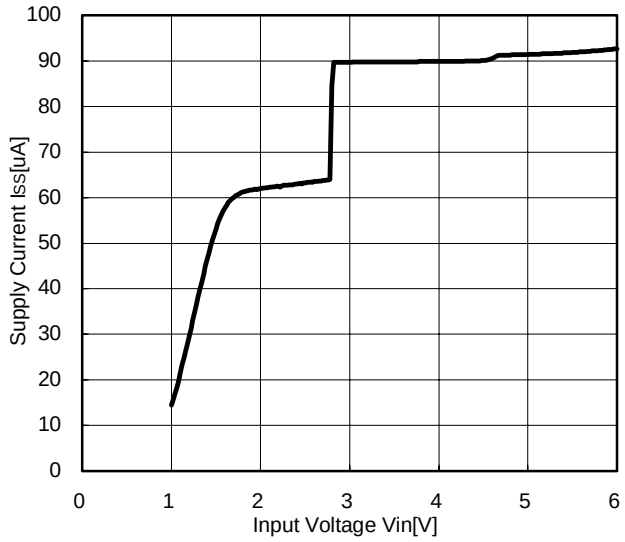

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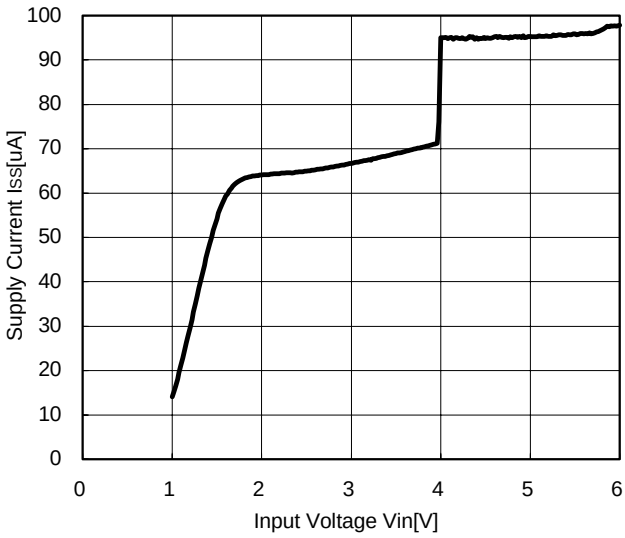

6) Supply Current vs. Temperature

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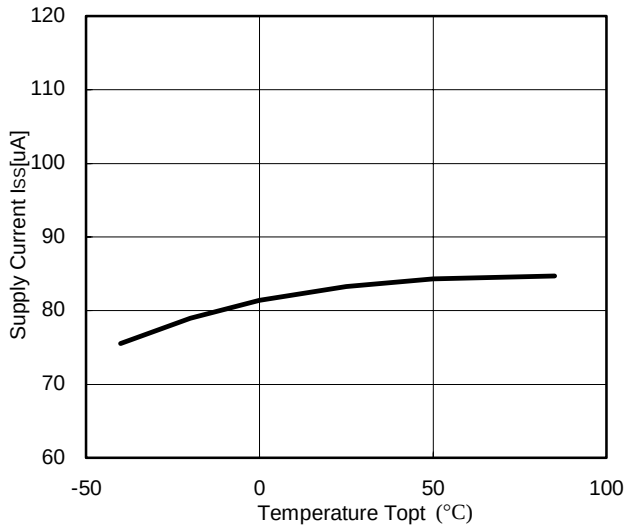
VIN=2.5V



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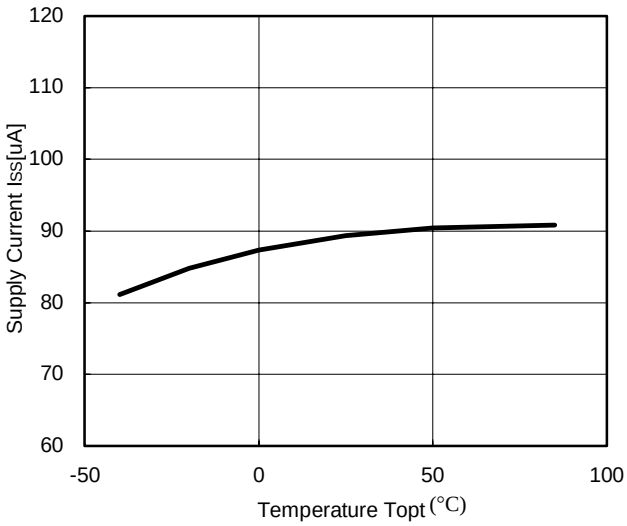
VIN=3.0V



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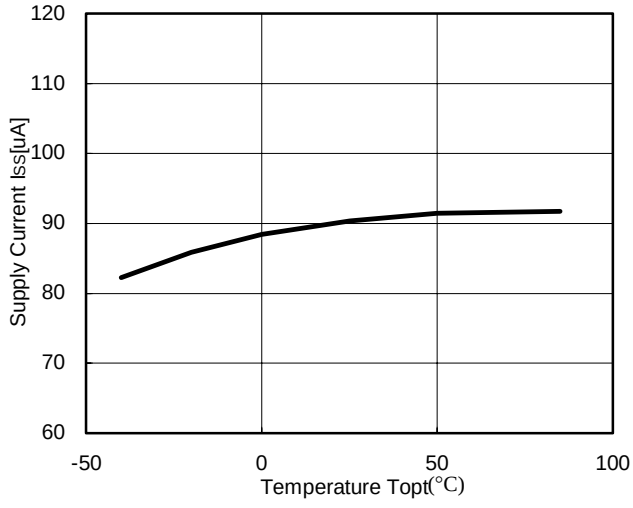
VIN=3.8V



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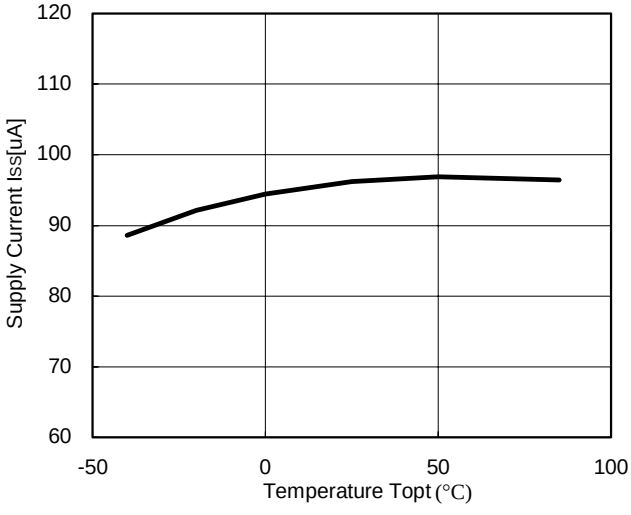
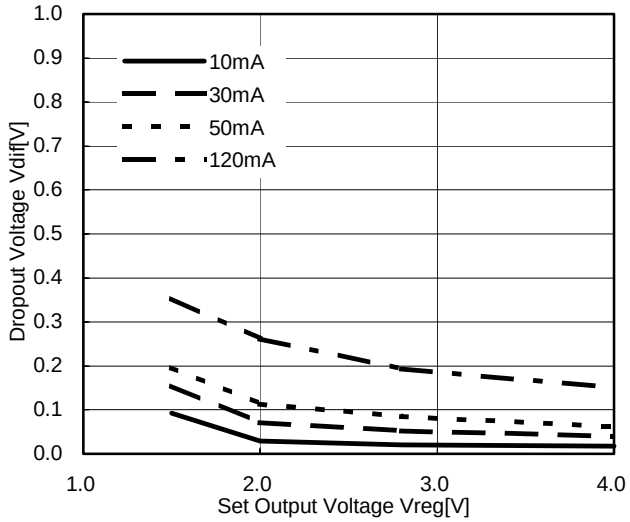
VIN=5.0V



7) Dropout Voltage vs. Set Output Voltage



8) Ripple Rejection vs. Frequency

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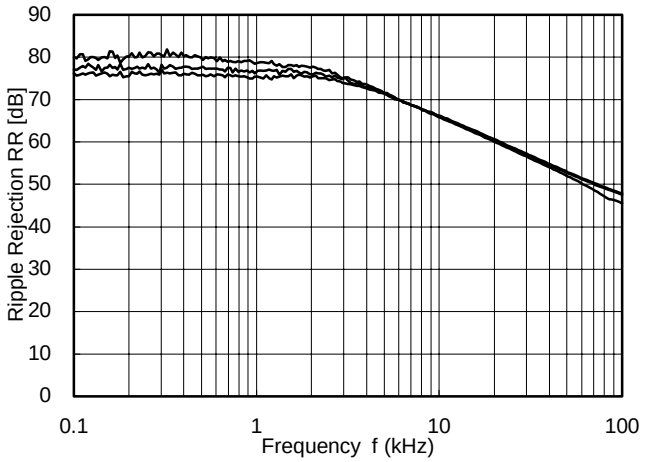
VIN=2.5V+0.5Vp-p, CIN = none, COUT = Ceramic 2.2µF



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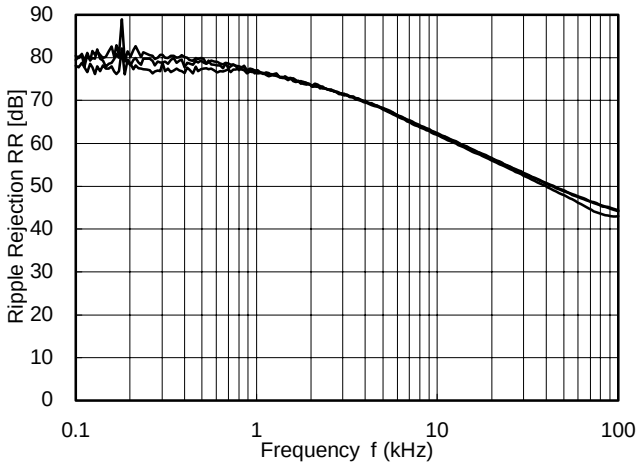
VIN=3.8V+0.5Vp-p, CIN = none, COUT = Ceramic 2.2µF



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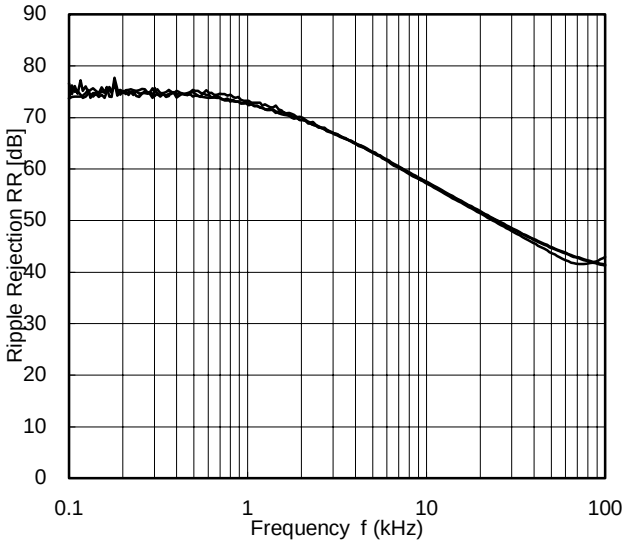
VIN=5.0V+0.5Vp-p, CIN = none, COUT = Ceramic 2.2µF



9) Ripple Rejection vs. Input Bias

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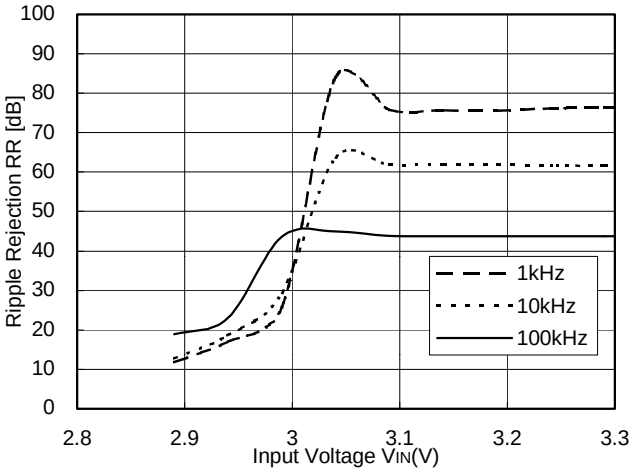
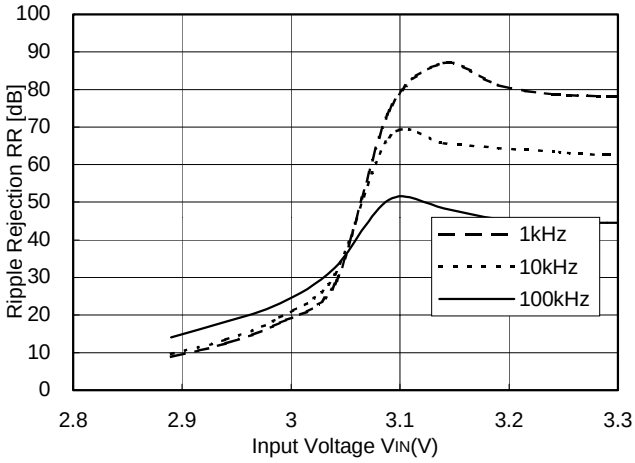
IOUT=1mA, CIN = none, COUT = Ceramic 2.2µF



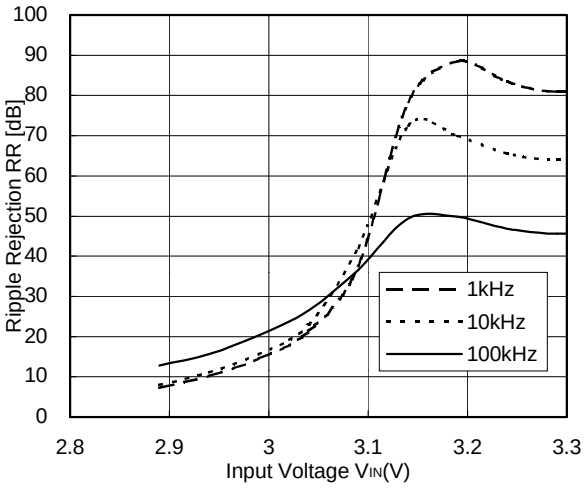
R1141Q281X

IOUT=30mA, CIN = none, COUT = Ceramic 2.2µF



R1141Q281X

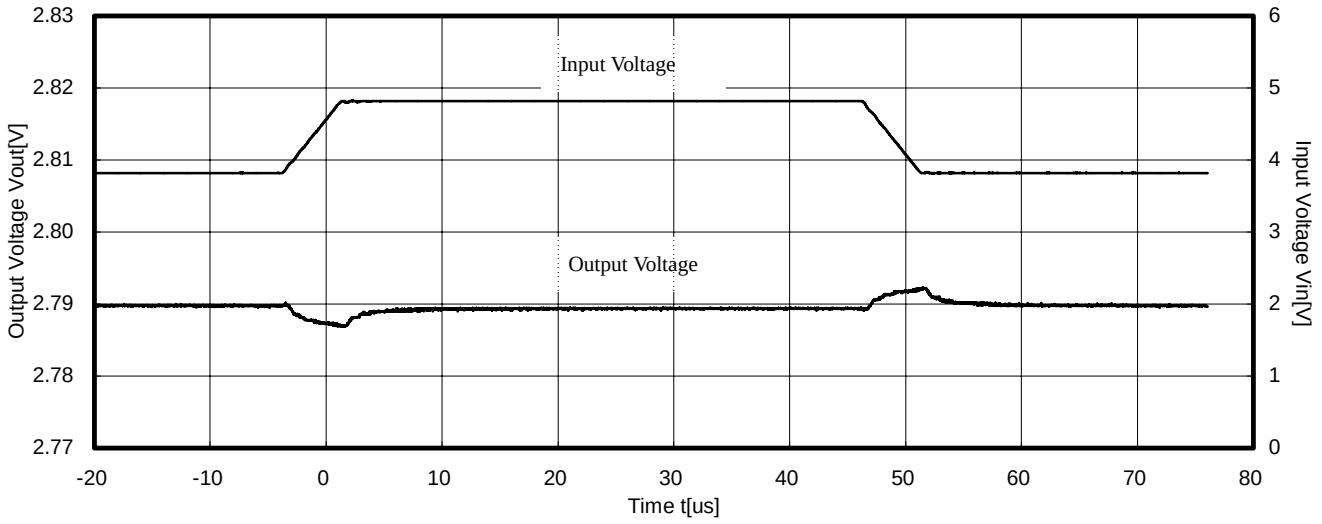
IOUT=50mA, CIN = none, COUT = Ceramic 2.2µF



10) Input Transient Response

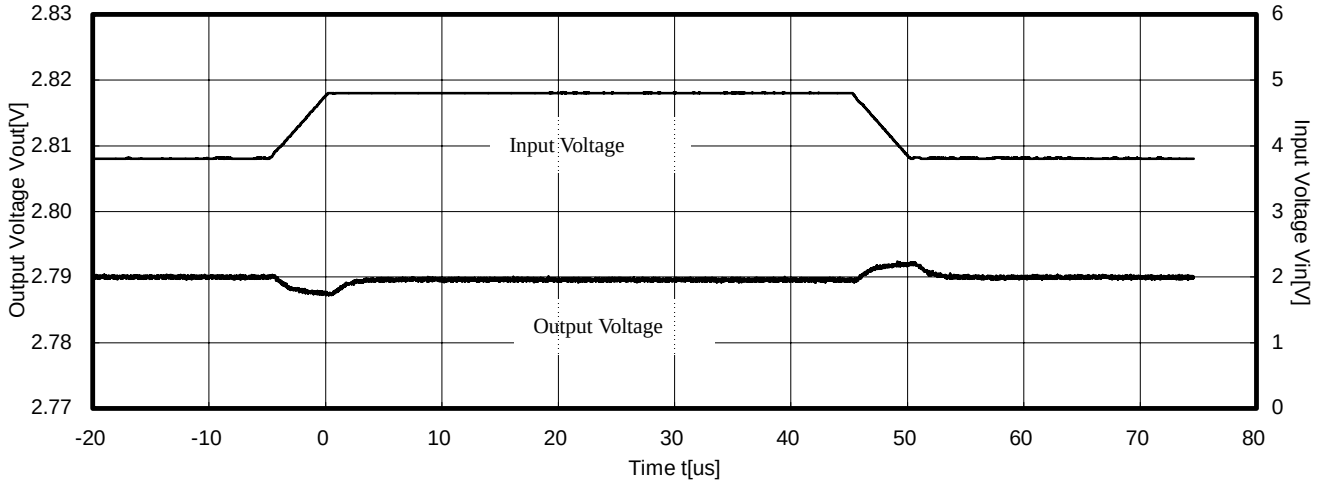
R1141Q281X

VIN=3.8V to 4.8V, IOUT=30mA, COUT = Ceramic 1.0µF, Tr=Tf=5.0µs



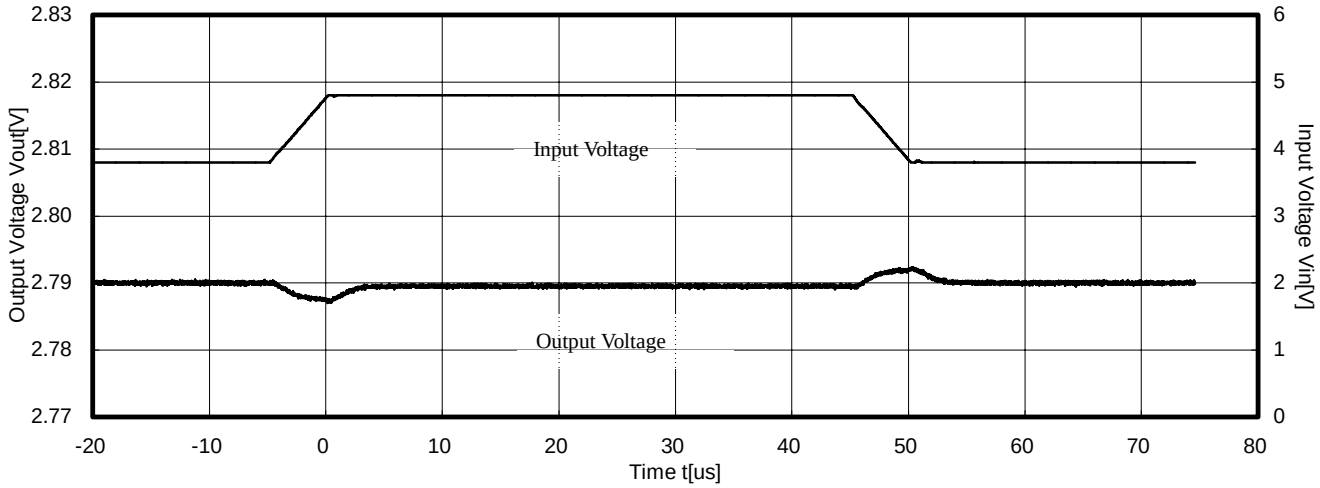
R1141Q281X

V_{IN}=3.8V to 4.8V, I_{OUT}=30mA, C_{OUT} = Ceramic 2.2µF, Tr=Tf=5.0µs



R1141Q281X

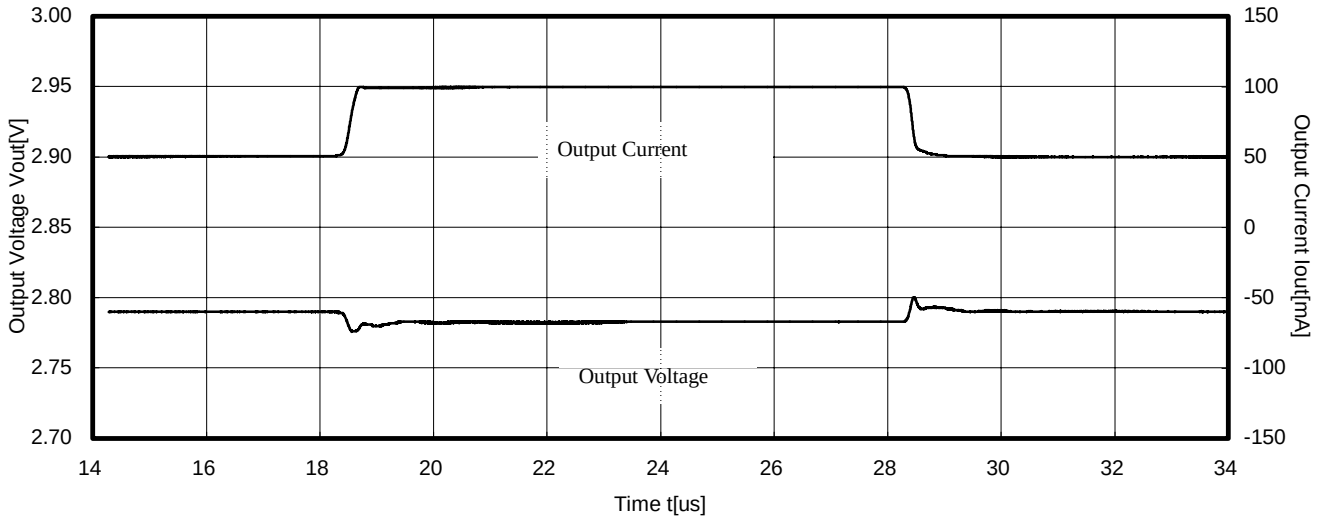
V_{IN}=3.8V to 4.8V, I_{OUT}=30mA, C_{OUT} = Ceramic 4.7µF, Tr=Tf=5.0µs



11) Load Transient Response

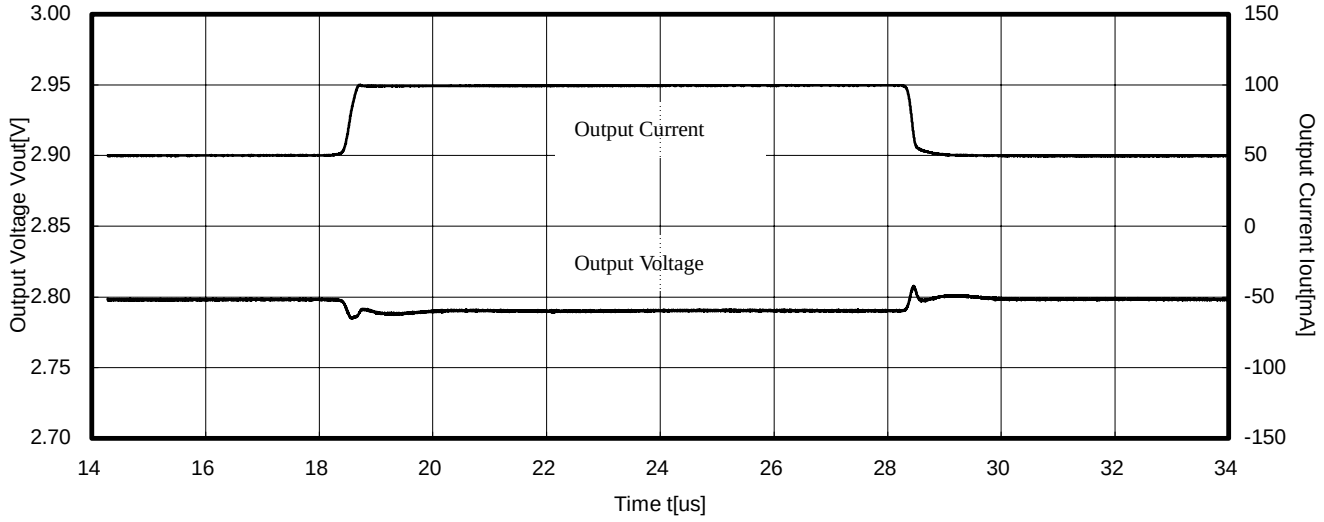
R1141Q281X

V_{IN}=3.8V, I_{OUT}=50mA→100mA, C_{IN} = Ceramic 1.0µF C_{OUT} = Ceramic 1.0µF, Tr=Tf=5.0µs



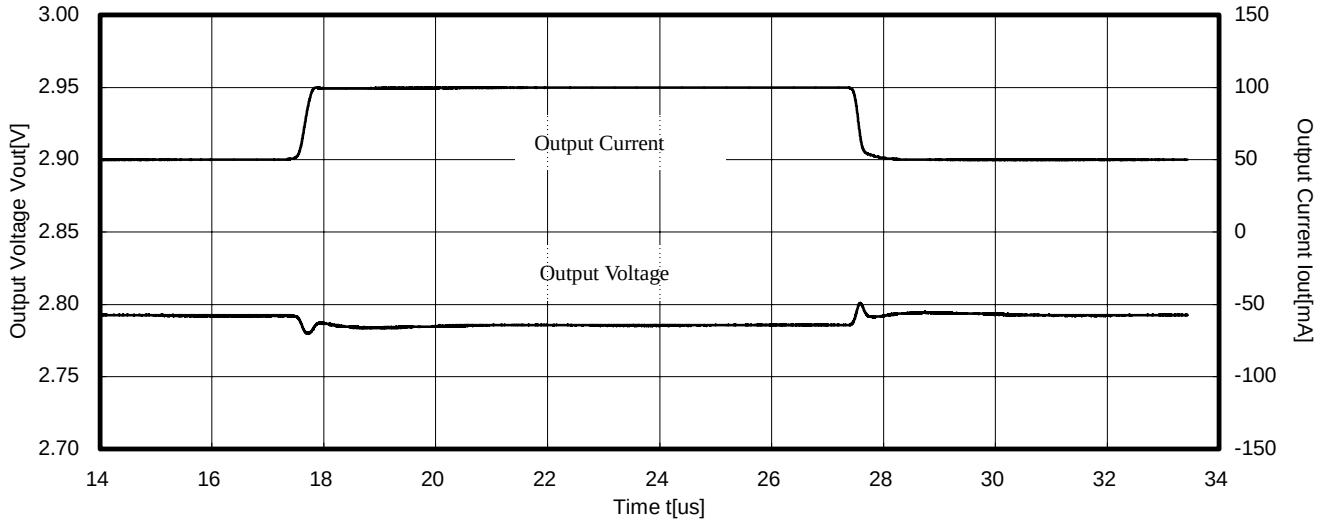
R1141Q281X

V_{IN}=3.8V, I_{OUT}=50mA→100mA, C_{IN} = Ceramic 1.0µF C_{OUT} = Ceramic 2.2µF, Tr=Tf=5.0µs



R1141Q281X

V_{IN}=3.8V, I_{OUT}=50mA→100mA, C_{IN} = Ceramic 1.0µF C_{OUT} = Ceramic 4.7µF, Tr=Tf=5.0µs



■ TECHNICAL NOTES

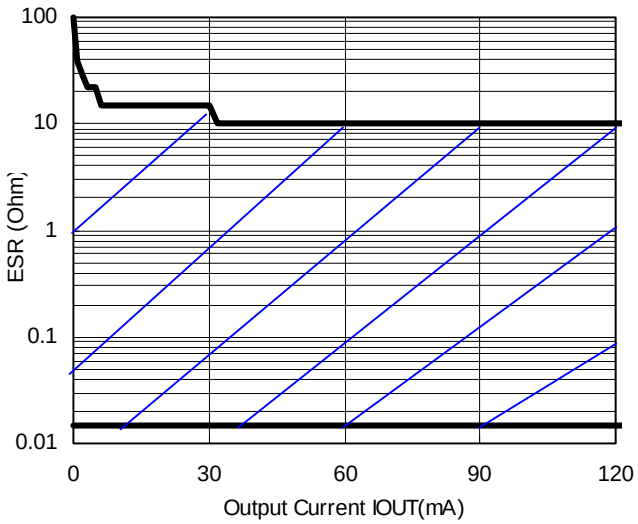
When using these ICs, consider the following points:
In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, be sure to use a capacitor C_{OUT} with good frequency characteristics and ESR (Equivalent Series Resistance) of which is in the range described as follows:

The relations between I_{OUT} (Output Current) and ESR of Output Capacitor are shown below. The conditions when the white noise level is under 40µV(Avg.) are marked as the hatched area in the graph.

<Test conditions>

(1) $V_{IN}=V_{SET}+1V$
(2) Frequency band: 10Hz to 30MHz
(3) Temperature: 25°C

R1141Q151X
f=10Hz to 2MHz, C_{IN} = Ceramic 1.0µF,
C_{OUT} = Ceramic 2.2µF



R1141Q281X
f=10Hz to 2MHz,C_{IN} = Ceramic1.0µF,
C_{OUT} = Ceramic2.2µF

